


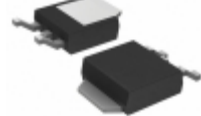



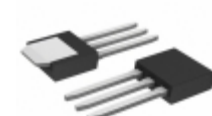
	<h2 style="color: red;">NTD50N03RT4</h2>
	<p>Hersteller-Teilenummer: NTD50N03RT4</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 25V 7.8A DPAK</p> <p>Datenblätter:  NTD50N03RT4.pdf</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, 12500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD50N03RT4
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 7.8A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	12500 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.5W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.8A (Ta), 45A (Tc)
Rds On (Max) @ Id, Vgs	12 mOhm @ 30A, 11.5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 11.5V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 12V
Verpackung	Tape & Reel (TR)



















































NTD50N03RT4 ist neu im Original, Suche NTD50N03RT4 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD50N03RT4 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD50N03RT4: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD50N03R-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A IPAK</p>	 <p>NTD50N03RT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A DPAK</p>	 <p>NTD50N06 VB NTD50N06 VB</p>	 <p>NTD50N03T4G O NTD50N03T4G O</p>
 <p>NTD517VS-TL-E SANYO SANYO SOT23-8</p>	 <p>NTD50N03R-035 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A IPAK</p>	 <p>NTD5406N ON NTD5406N ON</p>	 <p>NTD50N03R-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A IPAK</p>

heiße Teile

Mehr

 NTD4960N	 NTD4960N-1G	 NTD4960NT4G	 NTD4963N	 NTD4963N-1
 NTD4963N-1G	 NTD4963N-35G	 NTD4963NT4G	 NTD4965N	 NTD4965N-35G
 NTD4965NT4G	 NTD4969N	 NTD4969N-1	 NTD4969N-1G	 NTD4969NT4G
 NTD4970N	 NTD4970N-1	 NTD4970N-1G	 NTD4970N-35G	 NTD4970NT4G
 NTD50N03R-001	 NTD50N03R-035	 NTD50N03R-1G	 NTD50N03R-35G	 NTD50N03RG
 NTD50N03RT4G	 NTD50N03T4G	 NTD50N06	 NTD5406N	 NTD5406NG
 NTD5406NT4G	 NTD5406T4G	 NTD5407N	 NTD5407NG	 NTD5407NT4G
 NTD5412NT4G	 NTD5413N	 NTD5413NT4G	 NTD5414N	 NTD5414NT4G
 NTD5426NT4G	 NTD5802N	 NTD5802NT4G	 NTD5803N	 NTD5803NT4G
 NTD5804N	 NTD5804NG	 NTD5804NT4G	 NTD5805N	 NTD5805NG

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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